







SN74AC573 SCAS542H - OCTOBER 1995 - REVISED FEBRUARY 2024

SN74AC573 Octal D-type Transparent Latches with 3-State Outputs

1 Features

- Operation of 2V to 6V V _{CC}
- Inputs accept voltages to 6V
- Maximum t_{pd} of 9ns at 5V
- 3-State outputs drive bus lines directly

2 Applications

- **Buffer registers**
- Bidirectional bus drivers
- Working registers

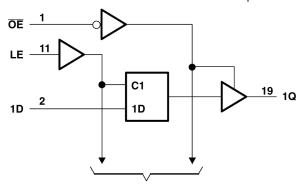
3 Description

These 8-bit latches feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. The devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)	BODY SIZE(3)
	RKS (VQFN, 20)	4.5 mm × 2.5 mm	4.5mm × 2.5mm
	DB (SSOP, 20)	7.2 mm × 7.8 mm	7.2mm x 5.30mm
	DGV (TVSOP, 20)	5 mm × 6.4 mm	5mm × 4.4mm
SN74AC573	DW (SOIC, 20)	12.8 mm × 10.3 mm	12.80mm x 7.50mm
	NS (SOP, 20)	12.6 mm × 7.8 mm	12.6mm x 5.3mm
	N (PDIP, 20)	24.33 mm × 9.4 mm	24.33mm x 6.35mm
	PW (TSSOP, 20)	6.5 mm × 6.4 mm	6.50mm x 4.40mm

- For more information, see Section 11. (1)
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



To Seven Other Channels

Logic Diagram (Positive Logic)

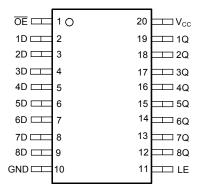


Table of Contents

1 Features1	7.1 Overview8
2 Applications1	7.2 Functional Block Diagram8
3 Description1	7.3 Device Functional Modes8
4 Pin Configuration and Functions3	8 Application and Implementation9
5 Specifications4	8.1 Power Supply Recommendations9
5.1 Absolute Maximum Ratings4	8.2 Layout9
5.2 Recommended Operating Conditions4	9 Device and Documentation Support10
5.3 Thermal Information5	9.1 Receiving Notification of Documentation Updates10
5.4 Electrical Characteristics5	9.2 Support Resources10
5.5 Timing Requirements, V _{CC} = 3.3 V ± 0.3 V5	9.3 Trademarks10
5.6 Timing Requirements, V _{CC} = 5 V ± 0.5 V6	9.4 Electrostatic Discharge Caution10
5.7 Switching Characteristics, V _{CC} = 3 V ± 0.3 V6	9.5 Glossary10
5.8 Switching Characteristics, V _{CC} = 5 V ± 0.5 V6	10 Revision History10
5.9 Operating Characteristics6	11 Mechanical, Packaging, and Orderable
6 Parameter Measurement Information7	Information10
7 Detailed Description8	



4 Pin Configuration and Functions



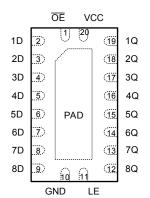


Figure 4-1. DB, DGV, DW, NS, N, or PW Packages, 20-Pin SSOP, TVSOP, SOIC, SOP, PDIP, or TSSOP (Top View)

Figure 4-2. RKS Package, 20-Pin VQFN (Top View)

Table 4-1. Pin Functions

	PIN	TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.	ITPE\''	DESCRIPTION
ŌĒ	1	1	Output enable
1D	2	1	1D input
2D	3	1	2D input
3D	4	1	3D input
4D	5	1	4D input
5D	6	1	5D input
6D	7	1	6D input
7D	8	1	7D input
8D	9	1	8D input
GND	10	_	Ground
LE	11	1	Latch enable input
8Q	12	0	8Q output
7Q	13	0	7Q output
6Q	14	0	6Q output
5Q	15	0	5Q output
4Q	16	0	4Q output
3Q	17	0	3Q output
2Q	18	0	2Q output
1Q	19	0	1Q output
V _{CC}	20	_	Power pin
Thermal I	Pad ⁽²⁾	_	The thermal pad can be connect to GND or left floating. Do not connect to any other signal or supply.

⁽¹⁾ I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.

⁽²⁾ For RKS package only.



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	+ 7	V
V _I ²	Input voltage range		-0.5	V _{CC} + 0.5	V
V _O ²	Output voltage range		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	$(V_I < 0 \text{ or } V_I > V_{CC})$		±20	mA
I _{OK}	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
Io	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		±50	mA
	Continuous current through, V _{CC} or GN	ID		±200	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)¹

	3 1 3 1		MIN	MAX	UNIT
V _{CC}	Supply voltage		2	6	V
		V _{CC} = 3 V	2.1		
V_{IH}	High-level input voltage	V _{CC} = 4.5 V	3.15		V
		V _{CC} = 5.5 V	3.85		
		V _{CC} = 3 V		0.9	
V_{IL}	Low-level input voltage	V _{CC} = 4.5 V		1.35	V
		V _{CC} = 5.5 V		1.65	
VI	Input voltage		0	V _{CC}	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 3 V		-12	
I _{OH}	High-level output current	V _{CC} = 4.5 V		-24	mA
		V _{CC} = 5.5 V		-24	
		V _{CC} = 3 V		12	
I _{OL}	Low-level output current	V _{CC} = 4.5 V		24	mA
		V _{CC} = 5.5 V		24	
Δt/Δν	Input transition rise or fall rate			8	ns/V
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND for proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



5.3 Thermal Information

THERMAL METRIC		DW (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	RKS (VQFN)	UNIT
		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	101.2	70	69	60	126.2	68	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	TA	= 25°C	SN74A	C573	LINUT
PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP MA	X MIN	MAX	UNIT
		3 V	2.9		2.9		
	I _{OH} = -50 μA	4.5 V	4.4		4.4		
		5.5 V	5.4		5.4		
V _{OH}	I _{OH} = −12 mA	3 V	2.58		2.48		V
	I = -24 mA	4.5 V	3.94		3.8		
	I _{OH} = −24 mA	5.5 V	4.94		4.8		
	$I_{OH} = -75 \text{ mA}^{(1)}$	5.5 V			3.85		
		3 V		(0.1	0.1	
	I _{OL} = 50 μA	4.5 V		().1	0.1	
		5.5 V		().1	0.1	
V _{OL}	I _{OL} = 12 mA	3 V		0.	36	0.44	V
	L = 24 mA	4.5 V		0.	36	0.44	
	I _{OL} = 24 mA	5.5 V		0.	36	0.44	
	I _{OL} = 75 mA	5.5 V				1.65	
I _I	V _I = V _{CC} or GND	5.5 V		±().1	±1	μA
I _{OZ}	V _O = V _{CC} or GND	5.5 V		±0.	25	±2.5	μA
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4	40	μA
Ci	V _I = V _{CC} or GND	5 V		5			pF

⁽¹⁾ Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

5.5 Timing Requirements, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T _A = 25°C MIN MAX		SN74AC573		UNIT
				MIN	MAX	UNIT
t _w	Pulse duration, LE high	6		7		ns
t _{su}	Setup time, data before LE↓	3.5		4		ns
t _h	Hold time, data after LE↓	2		2		ns

Copyright © 2024 Texas Instruments Incorporated

Submit Document Feedback



5.6 Timing Requirements, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T _A = 25°C		SN74A	C573	UNIT
		MIN	MAX	MIN	MAX	ONII
t _w	Pulse duration, LE high	4		5		ns
t _{su}	Setup time, data before LE↓	3		3.5		ns
t _h	Hold time, data after LE↓	2		2		ns

5.7 Switching Characteristics, $V_{CC} = 3 V \pm 0.3 V$

over recommended operating free-air temperature range, V_{CC} = 3 V \pm 0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	EDOM (INDUT)	TO (OUTPUT)	T _A = 2	5°C	SN74AC	573	UNIT
PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	MIN	MAX	UNII
t _{PLH}	. D	Q	2.5	13	2	15	no
t _{PHL}		Q	2.5	12	2	14	ns
t _{PLH}	LE	Q	2.5	13	2	15	no
t _{PHL}		Q	2.5	12	2	14	ns
t _{PZH}	ŌĒ	Q	2.5	11	2	12	no
t _{PZL}	OE	Q	2.5	11	2	12.5	ns
t _{PHZ}	ŌĒ	Q	2.5	12.5	2	13.5	ne
t _{PLZ}	OE	Q	2.5	9.5	2	10.5	ns

5.8 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	EDOM (INDUT)	TO (OUTPUT)	T _A = 25°	°C	SN74AC5	73	UNIT
PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	MIN	MAX	UNII
t _{PLH}	D	Q	2.5	10	2	11.5	
t _{PHL}	D	Q	2.5	9.5	2	11	ns
t _{PLH}	LE	Q	2.5	9.5	2	11	
t _{PHL}		Q	2.5	8.5	2	10	ns
t _{PZH}	- OE	Q	2.5	9	2	10	
t _{PZL}	- OE	Q	2.5	8.5	2	9.5	ns
t _{PHZ}	- ŌĒ		2.5	11	2	12	
t _{PLZ}	- OE	Q	2.5	8	2	9	ns

5.9 Operating Characteristics

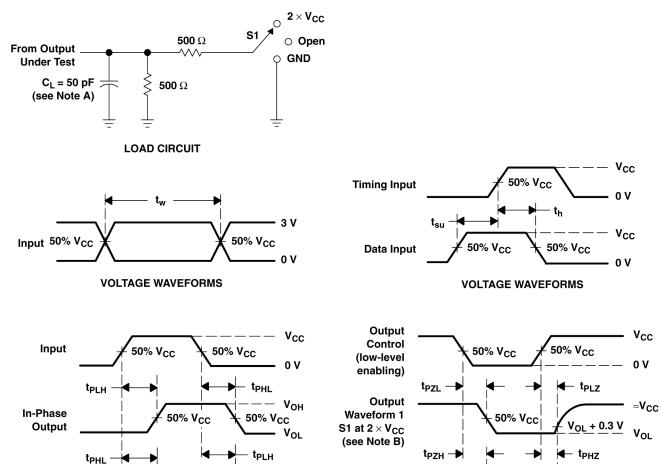
 V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	25	pF

Product Folder Links: SN74AC573



6 Parameter Measurement Information



VOLTAGE WAVEFORMS

VOLTAGE WAVEFORMS

50% V_{CC}

V_{OH} – 0.3 V

≈0 V

A. C_L includes probe and jig capacitance.

Out-of-Phase

Output

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

Output

Waveform 2

S1 at Open

(see Note B)

C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.

 \mathbf{v}_{OH}

 V_{OL}

D. The outputs are measured one at a time with one input transition per measurement.

50% V_{CC}

Figure 6-1. Load Circuit and Voltage Waveforms

Table 6-1.

TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	2 × V _{CC}
t _{PHZ} /t _{PZH}	Open

Copyright © 2024 Texas Instruments Incorporated

Submit Document Feedback



7 Detailed Description

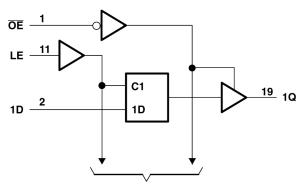
7.1 Overview

The eight latches are D-type transparent latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D Inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines in a bus-organized system without need for interface or pullup components.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

7.2 Functional Block Diagram



To Seven Other Channels

Figure 7-1. Logic Diagram (Positive Logic)

7.3 Device Functional Modes

Table 7-1. Function Table (Each Latch)

I	NPUTS ⁽¹⁾		OUTPUT ⁽²⁾ Q
OE	LE	D	OUIFUI() Q
L	Н	Н	Н
L	Н	L	L
L	L	Х	Q_0
Н	Х	Х	Z

- (1) H = High voltage level, L = Low voltage level, X = High or low voltage level
- (2) H = Driving high, L = Driving low, Q₀ = Driving previous high or low state, Z = High impedance

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the Section 5.2 table. The total current through Ground or V_{CC} must not exceed ± 70 mA as per Section 5.1 table.

Each V_{CC} pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends 0.1- μ F capacitor; if there are multiple V_{CC} pins, then TI recommends 0.01- μ F or 0.022- μ F capacitor for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1- μ F and 1- μ F capacitor are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

8.2 Layout

8.2.1 Layout Guidelines

When using multiple-bit logic devices, inputs must never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input and the gate are used, or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Layout Diagram specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, they are tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it disables the output section of the part when asserted. This does not disable the input section of the I/Os, so they cannot float when disabled.

8.2.2 Layout Example

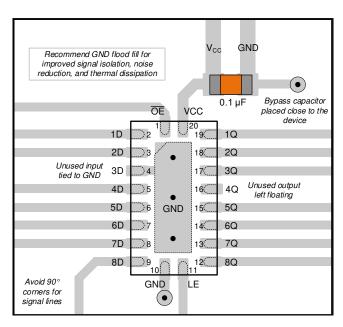


Figure 8-1. Layout example of the SN74AC573

Copyright © 2024 Texas Instruments Incorporated

Submit Document Feedback



9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (November 2023) to Revision H (February 2024)	Page
 Added body size to Package Information table	5
Added Application and Implementation section	9
Changes from Revision F (June 2023) to Revision G (November 2023)	Page
 Updated the Package Information table to include package lead size Added the RKS package information 	

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74AC573

www.ti.com

9-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74AC573DBR	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	(4) NIPDAU	(5) Level-1-260C-UNLIM	-40 to 85	AC573
SN74AC573DBR.A	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573
SN74AC573DBRG4	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573
SN74AC573DW	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-40 to 85	AC573
SN74AC573DWR	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573
SN74AC573DWR.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573
SN74AC573DWRG4	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573
SN74AC573N	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74AC573N
SN74AC573N.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74AC573N
SN74AC573NSR	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573
SN74AC573NSR.A	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573
SN74AC573PW	Obsolete	Production	TSSOP (PW) 20	-	-	Call TI	Call TI	-40 to 85	AC573
SN74AC573PWR	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573
SN74AC573PWR.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573
SN74AC573PWRE4	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573
SN74AC573RKSR	Active	Production	VQFN (RKS) 20	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AC573
SN74AC573RKSR.A	Active	Production	VQFN (RKS) 20	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AC573

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

PACKAGE OPTION ADDENDUM

www.ti.com 9-Nov-2025

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74AC573:

Automotive: SN74AC573-Q1

NOTE: Qualified Version Definitions:

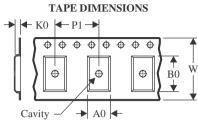
Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

www.ti.com 23-Jul-2025

TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AC573DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AC573DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AC573DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74AC573NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AC573PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AC573RKSR	VQFN	RKS	20	3000	180.0	12.4	2.8	4.8	1.2	4.0	12.0	Q1



www.ti.com 23-Jul-2025



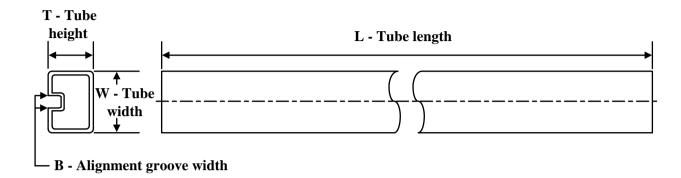
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AC573DBR	SSOP	DB	20	2000	353.0	353.0	32.0
SN74AC573DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74AC573DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74AC573NSR	SOP	NS	20	2000	356.0	356.0	45.0
SN74AC573PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74AC573RKSR	VQFN	RKS	20	3000	210.0	185.0	35.0

PACKAGE MATERIALS INFORMATION

www.ti.com 23-Jul-2025

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74AC573N	N	PDIP	20	20	506	13.97	11230	4.32
SN74AC573N.A	N	PDIP	20	20	506	13.97	11230	4.32

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC

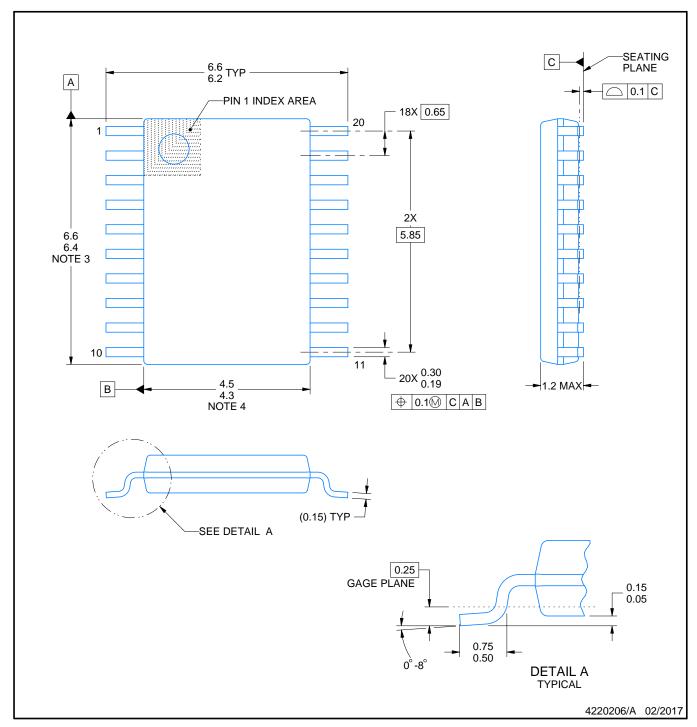


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







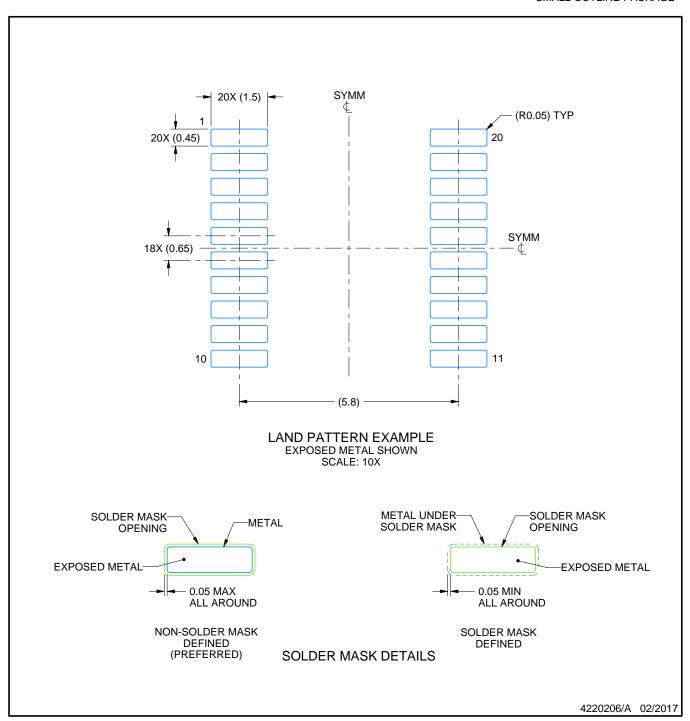
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



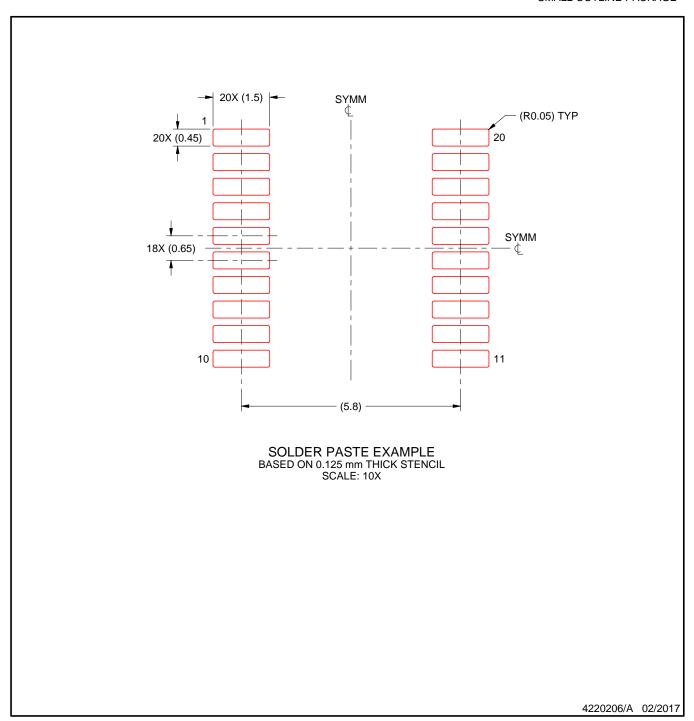


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



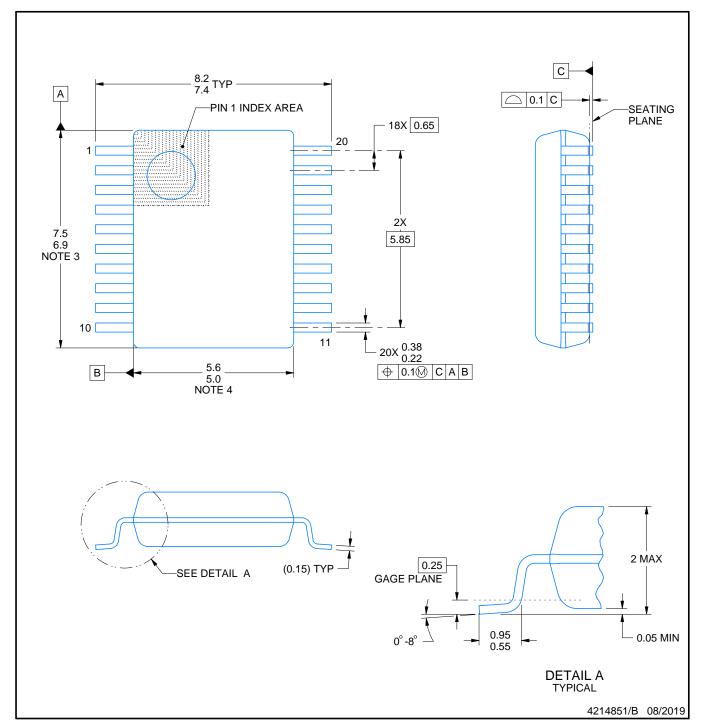


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







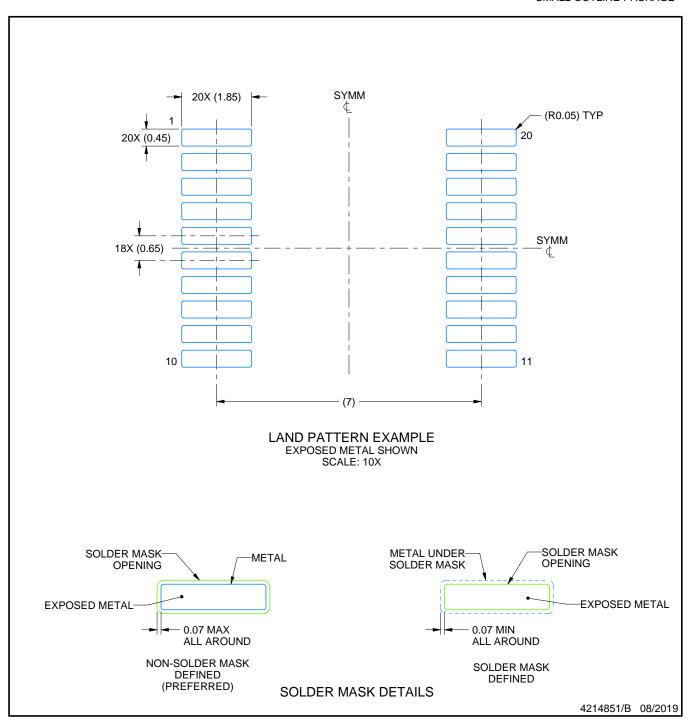
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



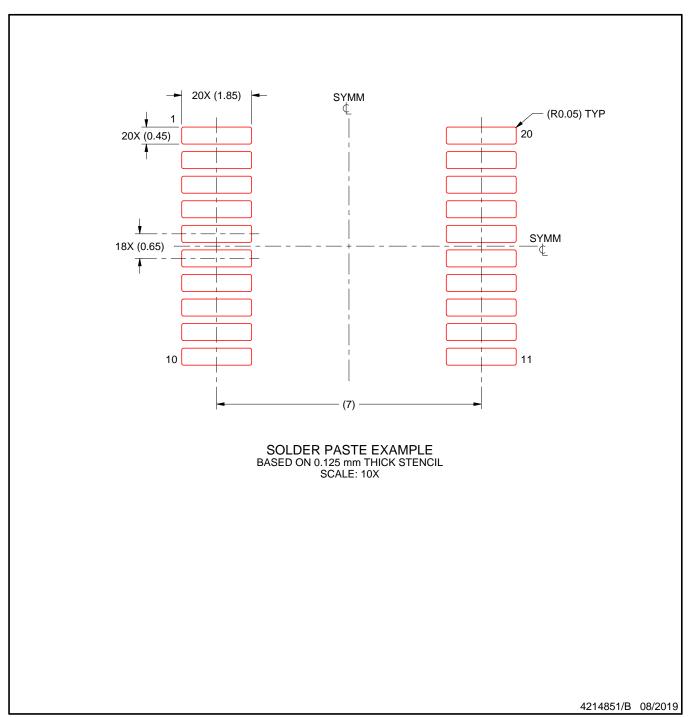


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

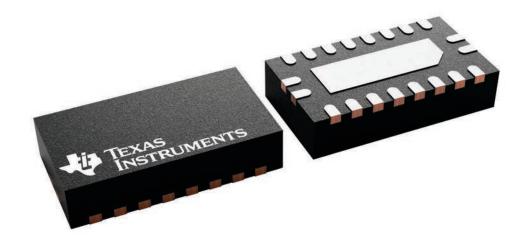
- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



2.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

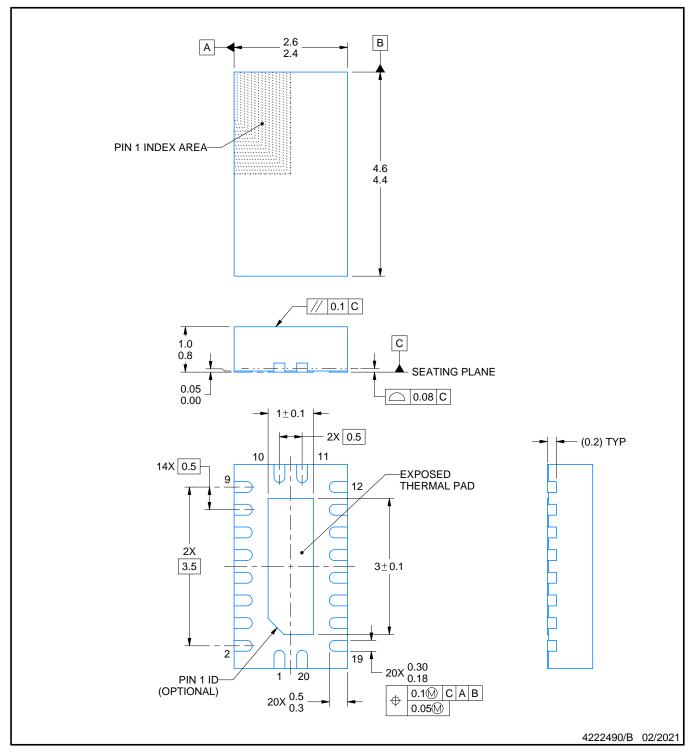
This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com



PLASTIC QUAD FLATPACK - NO LEAD

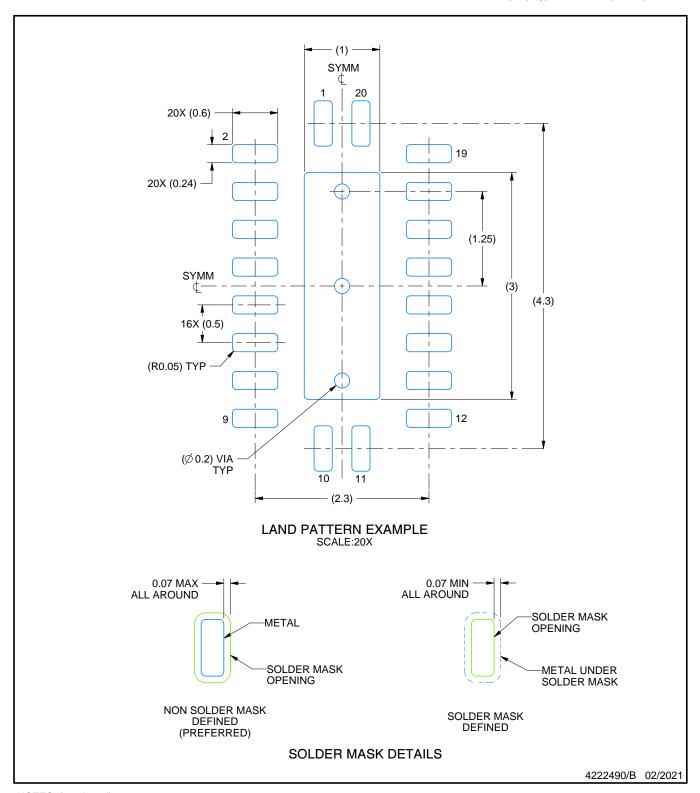


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

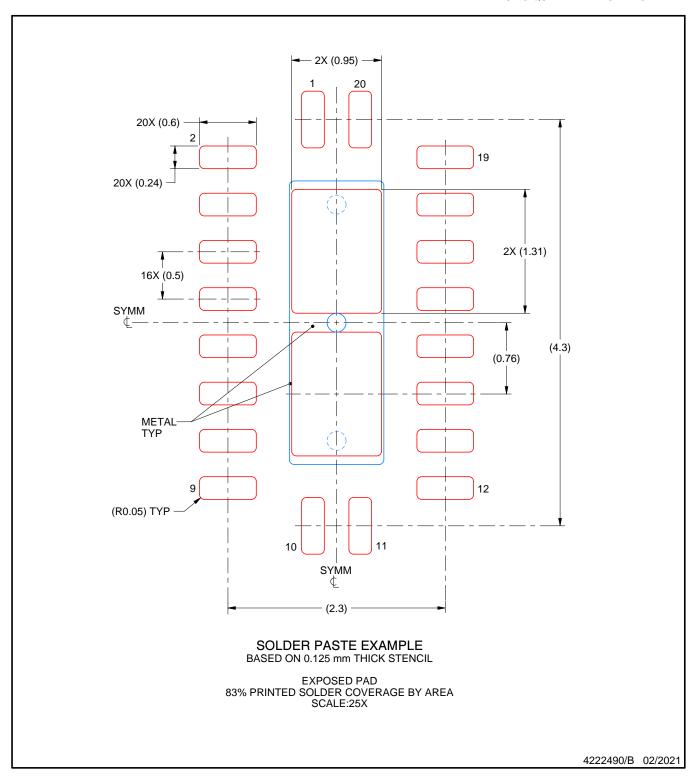


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025